

SCAS617E-OCTOBER 1998-REVISED MARCH 2005

## FEATURES

- Member of the Texas Instruments Widebus+™ Family
- Operates From 1.65 V to 3.6 V
- Inputs Accept Voltages to 5.5 V
- Max t<sub>pd</sub> of 4.1 ns at 3.3 V
- Typical V<sub>OLP</sub> (Output Ground Bounce) <0.8 V at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot) >2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> =  $25^{\circ}$ C
- Ioff Supports Partial-Power-Down Mode Operation

# DESCRIPTION/ORDERING INFORMATION

Supports Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V V<sub>cc</sub>)

- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

This 32-bit buffer/driver is designed for 1.65-V to 3.6-V  $V_{CC}$  operation.

The SN74LVCH32244A is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The device can be used as eight 4-bit buffers, four 8-bit buffers, two 16-bit buffers, or one 32-bit buffer. It provides true outputs and symmetrical active-low output-enable ( $\overline{OE}$ ) inputs.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

To ensure the high-impedance state during power up or power down, OE should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

#### **ORDERING INFORMATION**

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
40%C to 95%C	LFBGA – GKE		SN74LVCH32244AGKER	CH244A
–40°C to 85°C	LFBGA – ZKE (Pb-free)	Tape and reel	SN74LVCH32244AZKER	

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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GKE OR ZKE PACKAGE (TOP VIEW)										
1	2	3	4	5	6	_				
С	С	С	С	С	С					
С	С	С	С	С	С					
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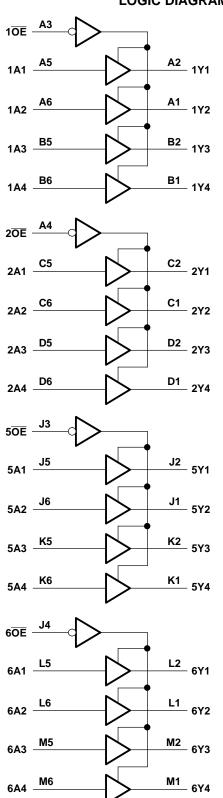
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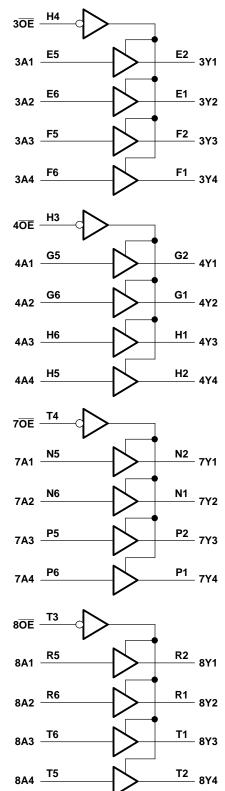
	1	2	3	4	5	6
Α	1Y2	1Y1	1 <del>0E</del>	2 <mark>0E</mark>	1A1	1A2
в	1Y4	1Y3	GND	GND	1A3	1A4
C	2Y2	2Y1	V <sub>CC</sub>	V <sub>CC</sub>	2A1	2A2
D	2Y4	2Y3	GND	GND	2A3	2A4
Ш	3Y2	3Y1	GND	GND	3A1	3A2
F	3Y4	3Y3	V <sub>CC</sub>	V <sub>CC</sub>	3A3	3A4
G	4Y2	4Y1	GND	GND	4A1	4A2
Η	4Y3	4Y4	4 <del>0E</del>	3 <mark>0E</mark>	4A4	4A3
L	5Y2	5Y1	5 <mark>0E</mark>	6 <del>0E</del>	5A1	5A2
κ	5Y4	5Y3	GND	GND	5A3	5A4
Г	6Y2	6Y1	V <sub>CC</sub>	V <sub>CC</sub>	6A1	6A2
Ν	6Y4	6Y3	GND	GND	6A3	6A4
Z	7Y2	7Y1	GND	GND	7A1	7A2
Ρ	7Y4	7Y3	V <sub>CC</sub>	V <sub>CC</sub>	7A3	7A4
R	8Y2	8Y1	GND	GND	8A1	8A2
Т	8Y3	8Y4	8 <mark>0E</mark>	7 <mark>0E</mark>	8A4	8A3

#### FUNCTION TABLE (EACH 4-BIT BUFFER)

INPU	JTS	OUTPUT
OE	Α	Y
L	Н	Н
L	L	L
н	Х	Z

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LOGIC DIAGRAM (POSITIVE LOGIC)

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#### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range	Supply voltage range			V
VI	Input voltage range <sup>(2)</sup>		-0.5	6.5	V
Vo	Voltage range applied to any output in the high-impedan	ce or power-off state <sup>(2)</sup>	-0.5	6.5	V
Vo	Voltage range applied to any output in the high or low st	ate <sup>(2)(3)</sup>	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current			±50	mA
	Continuous current through each V <sub>CC</sub> or GND			±100	mA
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	GKE/ZKE package		40	°C/W
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of  $V_{CC}$  is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

## **Recommended Operating Conditions**<sup>(1)</sup>

			MIN	MAX	UNIT
V	Supply voltage	Operating	1.65	3.6	V
V <sub>CC</sub>	Supply voltage	Data retention only	1.5		v
		V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65  imes V_{CC}$		
V <sub>IH</sub>	High-level input voltage	$V_{CC}$ = 2.3 V to 2.7 V	1.7		V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		
		V <sub>CC</sub> = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	
V <sub>IL</sub>	Low-level input voltage	$V_{CC}$ = 2.3 V to 2.7 V		0.7	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8	
VI	Input voltage		0	5.5	V
V	Output uskans	High or low state	0	V <sub>CC</sub>	V
Vo	Output voltage	3-state	0	5.5	v
		V <sub>CC</sub> = 1.65 V		-4	
	High lovel output ourrent	$V_{CC} = 2.3 V$		-8	mA
I <sub>OH</sub>	High-level output current	$V_{CC} = 2.7 V$		-12	ША
		$V_{CC} = 3 V$		-24	
		V <sub>CC</sub> = 1.65 V		4	
	Low lovel output ourrept	$V_{CC} = 2.3 V$		8	mA
I <sub>OL</sub>	Low-level output current	$V_{CC} = 2.7 V$		12	ШA
		$V_{CC} = 3 V$		24	
$\Delta t/\Delta v$	Input transition rise or fall rate			10	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

 All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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## **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP <sup>(1)</sup> MAX	UNIT	
	I <sub>OH</sub> = -100 μA	1.65 V to 3.6 V	V <sub>CC</sub> – 0.2			
V <sub>OH</sub>	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2			
	$I_{OH} = -8 \text{ mA}$	2.3 V	1.7			
	12 ~ 12 ~ 1	2.7 V	2.2		V	
	$I_{OH} = -12 \text{ mA}$	3 V	2.4			
	$I_{OH} = -24 \text{ mA}$	3 V	2.2			
	I <sub>OL</sub> = 100 μA	1.65 V to 3.6 V		0.2		
	I <sub>OL</sub> = 4 mA	1.65 V		0.45		
V <sub>OL</sub>	I <sub>OL</sub> = 8 mA	2.3 V		0.7	V	
	I <sub>OL</sub> = 12 mA	2.7 V		0.4		
	I <sub>OL</sub> = 24 mA	3 V		0.55		
I <sub>I</sub>	$V_1 = 0 \text{ to } 5.5 \text{ V}$	3.6 V		±5	μA	
	V <sub>1</sub> = 0.58 V	165 \/	25			
	V <sub>1</sub> = 1.07 V	1.65 V	-25			
	V <sub>1</sub> = 0.7 V	2.2.1/	45			
I <sub>I(hold)</sub>	V <sub>1</sub> = 1.7 V	2.3 V	-45		μΑ	
	V <sub>1</sub> = 0.8 V	0.14	75			
	V <sub>1</sub> = 2 V	3 V	-75			
	$V_1 = 0$ to 3.6 V <sup>(2)</sup>	3.6 V		±500		
I <sub>off</sub>	$V_1 \text{ or } V_0 = 5.5 \text{ V}$	0		±10	μA	
I <sub>OZ</sub>	V <sub>O</sub> = 0 to 5.5 V	3.6 V		±10	μΑ	
	$V_1 = V_{CC} \text{ or } GND$	2.6.1/		40		
I <sub>CC</sub>	$\frac{1}{3.6 \text{ V} \le \text{V}_1 \le 5.5 \text{ V}^{(3)}}  I_{\text{O}} = 0$	3.6 V		40	μA	
$\Delta I_{CC}$	One input at $V_{CC} - 0.6 V$ , Other inputs at $V_{CC}$ or GND	2.7 V to 3.6 V		500	μΑ	
Ci	$V_1 = V_{CC}$ or GND	3.3 V		5.5	pF	
Co	$V_{O} = V_{CC}$ or GND	3.3 V		6	pF	

(1)

All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C. This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to (2) another.

This applies in the disabled state only. (3)

### **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTBUT)	V <sub>CC</sub> = ± 0.1	1.8 V 5 V	V <sub>CC</sub> = 2 ± 0.2		V <sub>CC</sub> =	2.7 V	V <sub>CC</sub> = 3 ± 0.3	3.3 V 8 V	UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	А	Y	(1)	(1)	(1)	(1)		4.7	1.1	4.1	ns
t <sub>en</sub>	OE	Y	(1)	(1)	(1)	(1)		5.8	1	4.6	ns
t <sub>dis</sub>	OE	Y	(1)	(1)	(1)	(1)		6.2	1.8	5.8	ns
t <sub>sk(o)</sub>										1.5	ns

(1) This information was not available at the time of publication.

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# **Operating Characteristics**

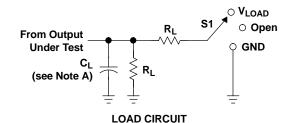
 $T_A = 25^{\circ}C$ 

PARAMETER		TEST CONDITIONS	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	UNIT	
C	Dower dissinction expectation	Outputs enabled	f = 10 MHz	(1)	(1)	34	ρF
C <sub>pd</sub>	Power dissipation capacitance	Outputs disabled		(1)	(1)	4	рг

(1) This information was not available at the time of publication.

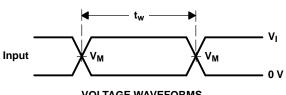
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#### PARAMETER MEASUREMENT INFORMATION

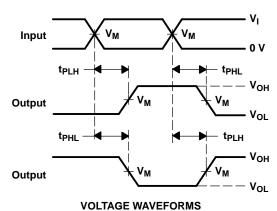


TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>LOAD</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

	INF	PUTS		VLOAD	•	-	
V <sub>CC</sub>	VI t <sub>r</sub> /t <sub>f</sub>		t <sub>r</sub> /t <sub>f</sub> V <sub>M</sub>		CL	RL	$V_\Delta$
1.8 V $\pm$ 0.15 V	V <sub>CC</sub>	≤ <b>2</b> ns	V <sub>CC</sub> /2	$2 \times V_{CC}$	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	V <sub>CC</sub>	≤2 ns	V <sub>CC</sub> /2	$2 \times V_{CC}$	30 pF	<b>500</b> Ω	0.15 V
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V
3.3 V $\pm$ 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V

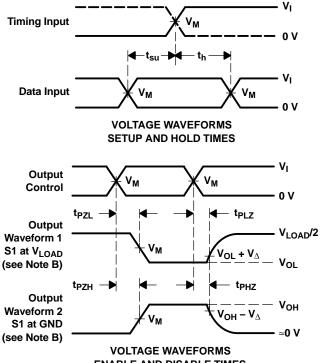


VOLTAGE WAVEFORMS PULSE DURATION



**PROPAGATION DELAY TIMES** 

INVERTING AND NONINVERTING OUTPUTS



#### ENABLE AND DISABLE TIMES LOW- AND HIGH-LEVEL ENABLING

- NOTES: A.  $C_{\mbox{L}}$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z\_O = 50  $\Omega$ .
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
  - H. All parameters and waveforms are not applicable to all devices.

#### Figure 1. Load Circuit and Voltage Waveforms



11-Apr-2013

# PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
SN74LVCH32244AGKER	NRND	LFBGA	GKE	96	1000	TBD	SNPB	Level-2-235C-1 YEAR	-40 to 85	CH244A	
SN74LVCH32244AZKER	ACTIVE	LFBGA	ZKE	96	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	-40 to 85	CH244A	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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# PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVCH32244AGKER	LFBGA	GKE	96	1000	330.0	24.4	5.7	13.7	2.0	8.0	24.0	Q1
SN74LVCH32244AZKER	LFBGA	ZKE	96	1000	330.0	24.4	5.7	13.7	2.0	8.0	24.0	Q1

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

18-Nov-2013



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVCH32244AGKER	LFBGA	GKE	96	1000	336.6	336.6	41.3
SN74LVCH32244AZKER	LFBGA	ZKE	96	1000	336.6	336.6	41.3

GKE (R-PBGA-N96)

PLASTIC BALL GRID ARRAY



- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Falls within JEDEC MO-205 variation CC.
  - D. This package is tin-lead (SnPb). Refer to the 96 ZKE package (drawing 4204493) for lead-free.



ZKE (R-PBGA-N96)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Falls within JEDEC MO-205 variation CC.

D. This package is lead-free. Refer to the 96 GKE package (drawing 4188953) for tin-lead (SnPb).



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